TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

2SK3320

For Low Noise Audio Amplifier Applications

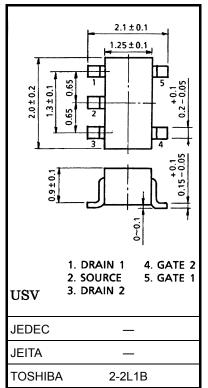
- Two devices in a ultra super mini (five pins) package
- High $|Y_{fs}|$: $|Y_{fs}| = 15 \text{ mS}$ (typ.) (V_{DS} = 10 V, V_{GS} = 0)
- High breakdown voltage: $V_{GDS} = -50 V$
- Super low noise: NF = 1.0dB (typ.)

 $(V_{DS} = 10 \text{ V}, \text{ I}_{D} = 0.5 \text{ mA}, \text{ f} = 1 \text{ kHz}, \text{ R}_{G} = 1 \text{ k}\Omega)$

• High input impedance: $I_{GSS} = -1 nA (max) (V_{GS} = -30 V)$

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	V _{GDS}	-50	V
Gate current	lG	10	mA
Drain power dissipation	P _D (Note 1)	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C



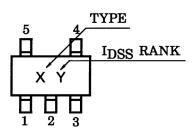
Weight: 6.2 mg (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

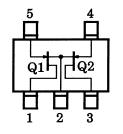
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

Marking



Pin Assignment (top view)



Unit: mm

Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

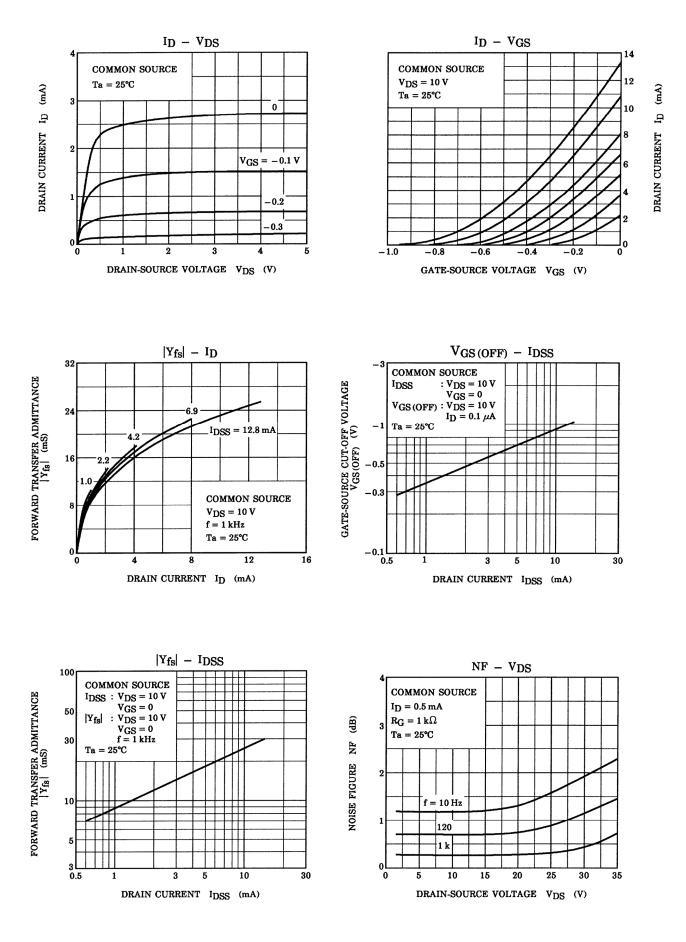
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I _{GSS}	$V_{GS} = -30 \text{ V}, \text{ V}_{DS} = 0$	_	_	-1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0, I_G = -100 \ \mu A$	-50	_	_	V
Drain current	I _{DSS} (Note)	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0$	1.2	_	14.0	mA
Gate-source cut-off voltage	V _{GS (OFF)}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 0.1 \mu\text{A}$	-0.2	_	-1.5	V
Forward transfer admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ kHz}$	4.0	15	_	mS
Input capacitance	C _{iss}	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$	_	13	_	pF
Reverse transfer capacitance	C _{rss}	$V_{DG} = 10 V, I_D = 0, f = 1 MHz$	_	3	_	pF
Noise figure	NF (1)	V_{DS} = 10 V, R_G = 1 k $\Omega,~I_D$ = 0.5 mA, f = 10 Hz	_	5	_	dB
	NF (2)	V_{DS} = 10 V, R_G = 1 k $\Omega,~I_D$ = 0.5 mA, f = 1 kHz		1		

Note 2: I_{DSS} classification Y (Y): 1.2~3.0 mA, GR (G): 2.6~6.5 mA, BL (L): 6.0~14.0 mA

().....I_{DSS} rank marking

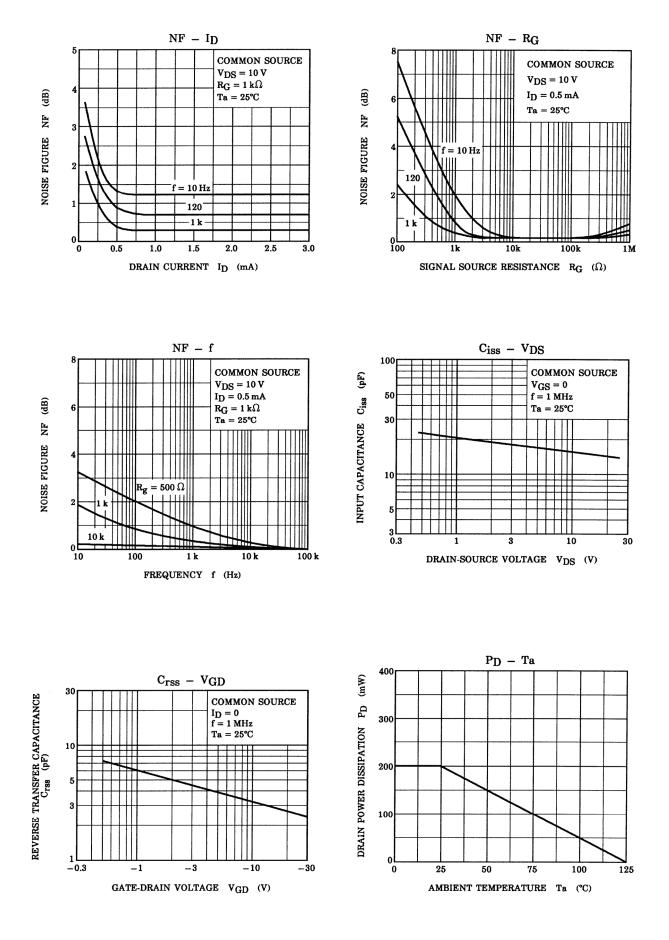
TOSHIBA

(Q1, Q2 common)



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(Q1, Q2 common)



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20070701-EN GENERAL

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